

ALPHANUMERIC INDEX — CROSS-REFERENCE (Continued)

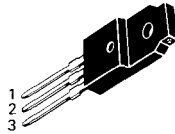
Industry Part Number	Motorola Direct Replacement	Motorola Similar Replacement	Page Number	Industry Part Number	Motorola Direct Replacement	Motorola Similar Replacement	Page Number
BDT63A	BDW41		3-328	BDW51C	2N5882		3-123
BDT63B	BDW42		3-328	BDW52	2N3791		3-56
BDT63C	BDW43		3-328	BDW52A	2N3792		3-56
BDT64	BDW44		3-328	BDW52B	2N3792		3-56
BDT64A	BDW45		3-328	BDW52C	2N5880		3-123
BDT64B	BDW46		3-328	BDW53	TIP120		3-1098
BDT64C	BDW47		3-328	BDW53A	TIP120		3-1098
BDT65	BDW40		3-328	BDW53B	TIP121		3-1098
BDT65A	BDW41		3-328	BDW53C	BDX53C		3-338
BDT65B	BDW42		3-328	BDW53D	BDX53D		3-338
BDT65C	BDW43		3-328	BDW54	TIP125		3-1098
BDT91	BD807		3-316	BDW54A	TIP125		3-1098
BDT92	BD808		3-318	BDW54B	TIP126		3-1098
BDT93	BD809		3-316	BDW54C	BDX54C		3-338
BDT94	BD810		3-318	BDW54D	BDX54D		3-338
BDV64	BDV64		3-324	BDW55	BD135		3-258
BDV64A	BDV64A		3-324	BDW56	BD136		3-260
BDV64B	BDV64B		3-324	BDW57	BD137		3-258
BDV64C		BDV64B	3-324	BDW58	BD138		3-260
BDV65	BDV65		3-324	BDW59	BD139		3-258
BDV65A	BDV65A		3-324	BDW60	BD140		3-260
BDV65B	BDV65B		3-324	BDW63	BDX53		3-338
BDV65C		BDV65B	3-324	BDW63A	BDX53A		3-338
BDV66C	MJH11018		3-1034	BDW63B	BDX53B		3-338
BDV66C	MJH11017		3-1034	BDW63C	BDX53C		3-338
BDV66D	MJH11019		3-1034	BDW63D	BDX53D		3-338
BDV67D	MJH11020		3-1034	BDW64	BDX54		3-338
BDV91	MJE3055T		3-904	BDW64A	BDX54A		3-338
BDV92	TIP34B		3-1077	BDW64B	BDX54B		3-338
BDV93	TIP34C		3-1077	BDW64C	BDX54C		3-338
BDV94	TIP2955		3-1108	BDW73	BD895		3-320
BDV95	TIP33B		3-1077	BDW73A	BD897		3-320
BDV96	TIP33C		3-1077	BDW73B	BD899		3-320
BDW21	2N3714		3-26	BDW73C	BD901		3-320
BDW21A	2N3714		3-26	BDW73D	BDX33D		3-334
BDW21B	2N3714		3-26	BDW74	BD896		3-322
BDW21C		2N5882	3-123	BDW74A	BD898		3-322
BDW22	2N3789		3-56	BDW74B	BD900		3-322
BDW22A	2N3789		3-56	BDW74C	BD902		3-322
BDW22B	2N3790		3-56	BDW74D	BDX34D		3-334
BDW22C	2N5880		3-123	BDW83	BDV65		3-324
BDW23	BDX53		3-338	BDW83A	BDV65		3-324
BDW23A	BDX53A		3-338	BDW83B	BDV65A		3-324
BDW23B	BDX53B		3-338	BDW83C	BDV65B		3-324
BDW23C	BDX53C		3-338	BDW84	BDV64		3-324
BDW24	BDX54		3-338	BDW84A	BDV64		3-324
BDW24A	BDX54A		3-338	BDW84B	BDV64A		3-324
BDW24B	BDX54B		3-338	BDW84C	BDV64B		3-324
BDW24C	BDX54C		3-338	BDW93	BDW39		3-328
BDW39	BDW39		3-328	BDW93A	BDW40		3-328
BDW40	BDW40		3-328	BDW93B	BDW41		3-328
BDW41	BDW41		3-328	BDW93C	BDW42		3-328
BDW42	BDW42		3-328	BDW94	BDW44		3-328
BDW44	BDW44		3-328	BDW94A	BDW45		3-328
BDW45	BDW45		3-328	BDW94B	BDW46		3-328
BDW46	BDW46		3-328	BDW94C	BDW47		3-328
BDW47	BDW47		3-328	BDX10	2N3055A		3-9
BDW51	2N3715		3-26	BDX10-4	2N3055A		3-9
BDW51A	2N3715		3-26	BDX10-6	2N3055A		3-9
BDW51B	2N3716		3-26	BDX10-7	2N3055A		3-9

*Consult Motorola if a direct replacement is necessary.

TABLE 5 — PLASTIC TO-220 (continued)

I _C Cont Amps Max	V _{CEO(sus)} Volts Min	Device Type		h _{FE} Min/Max	@ I _C Amp	Resistive Switching			f _T MHz Min	P _D (Case) Watts @ 25°C
		NPN	PNP			t _s μs Max	t _f μs Max	@ I _C Amp		
10	60	D44H7	D45H7	20 min	4					50
		D44H8	D45H8	40 min	4					50
			D45H9	40 min	4					50
		MJE2801T		25/100	3					75
		MJE3055T	MJE2955T	20/70	4					75
		2N6387##	2N6667##	1k/20k	5				20#	65
		SE9300##	SE9400##	1k min	4				1#	70
	80	BDX33B##	BDX34B##	750 min	3				3	70
		BD809	BD810	15 min	4				1.5	90
		D44E3##		1000 min	5	2 typ	0.5 typ	10		50
			D45H12	40 min	4					50
		2N6388##	2N6668##	1k/20k	5				20#	65
		D44H10	D45H10	20 min	4	0.5 typ	0.14 typ	5	50 typ	50
12	300	D44H11	D45H11	40 min	4	0.5 typ	0.14 typ	5	50 typ	50
		SE9301##	SE9401##	1k min	4				1#	70
		BDX33C##	BDX34C##	750 min	3				3	70
		SE9302##	SE9402##	1k min	4				1#	70
		MJE13008		6/30	8	3	0.7	8	4	100
		MJE13009		6/30	8	3	0.7	8	4	100
	400	D44VH1	D45VH1	20 min	4	0.7	0.09	8	50 typ	83
		2N6486	2N6489	20/150	5	0.6 typ	0.3 typ	5	5	75
		BDW39	BDW44	1 k min	5	1 typ	1.5 typ	5	4	85
		D44VH4	D45VH4	20 min	4	0.5	0.09	8	50 typ	83
		2N6487	2N6490	20/150	5	0.6 typ	0.3 typ	5	5	75
		BDW40	BDW45	1 k min	5	1 typ	1.5 typ	5	4	85
15	30	D44VH7		20 min	4	0.5	0.09	8	50 typ	85
		2N6488	2N6491	20/150	5	0.6 typ	0.3 typ	5	5	75
		BDW41	BDW46	1 k min	5	1 typ	1.5 typ	5	4	85
		D44VH10	D45VH10	20 min	4	0.5	0.09	8	50 typ	83
		BDW42	BDW47	1 k min	5	1 typ	1.5 typ	5	4	85
		BDW43	BDW48	1 k min	5	1 typ	1.5 typ	5	4	85

|h_{FE}| @ 1 MHz, ## Darlington

TABLE 6 — PLASTIC Full Pak (TO-220 Type)

CASE 221C-02

I _C Cont Amps Max	V _{CEO(sus)} Volts Min	Device Type		h _{FE} Min/Max	@ I _C Amp	Resistive Switching			f _T MHz Min	P _D (Case) Watts @ 25°C
		NPN	PNP			t _s μs Max	t _f μs Max	@ I _C Amp		
1	250	MJF47		30/150	0.3	2 typ	0.17 typ	0.3	10	28
5	100	MJF122##	MJF127##	2000 min	3	1.5 typ	1.5 typ	3	4#	28
8	80		MJF6107	30/90	2	0.5 typ	0.13 typ	2	4	35
	100	MJF102##	MJF107##	3000 min	3	1.5 typ	1.5 typ	3	4#	35
	150	MJF15030	MJF15031	40 min	3	1 typ	0.15 typ	3	30	35
10	60	MJF3055	MJF2955	20/100	4				2	40

|h_{FE}| @ 1 MHz, ## Darlington

MOTOROLA SEMICONDUCTOR TECHNICAL DATA

**NPN
BDW39
thru
BDW43**

**PNP
BDW44
thru
BDW48**

DARLINGTON COMPLEMENTARY SILICON POWER TRANSISTORS

... designed for general purpose and low speed switching applications.

- High DC Current Gain — $h_{FE} = 2500$ (typ.) @ $I_C = 5.0$ Adc.
- Collector Emitter Sustaining Voltage @ 30 mAdc:
 $V_{CE(sus)} = 45$ Vdc (min.) — BDW39/BDW44
 60 Vdc (min.) — BDW40/BDW45
 80 Vdc (min.) — BDW41/BDW46
 100 Vdc (min.) — BDW42/BDW47
 120 Vdc (min.) — BDW43/BDW48
- Low Collector Emitter Saturation Voltage:
 $V_{CE(sat)} = 2.0$ Vdc (max.) @ $I_C = 5.0$ Adc
 3.0 Vdc (max.) @ $I_C = 10.0$ Adc
- Monolithic Construction with Built-In Base Emitter Shunt resistors
- TO-220AB Compact Package
- TO-66 Lead form also available ordered with "-66" suffix.

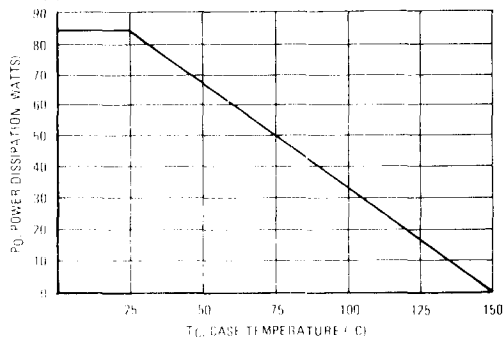
MAXIMUM RATINGS

Rating	Symbol	BDW39 BDW44	BDW40 BDW45	BDW41 BDW46	BDW42 BDW47	BDW43 BDW48	Unit
Collector Emitter Voltage	V_{CE}	45	60	80	100	120	V_{dc}
Collector Base Voltage	V_{CB}	45	60	80	100	120	V_{dc}
Emitter Base Voltage	V_{EB}	5.0					V_{dc}
Collector Current - Continuous	I_C	15					A _{dc}
Base Current	I_B	0.5					A _{dc}
Total Device Dissipation at $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	85 0.68					Watts W/°C
Operating and Storage Junction Temperature Range	T_J, T_{stg}	55 to -150					°C

THERMAL CHARACTERISTICS

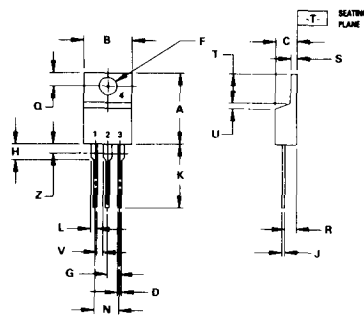
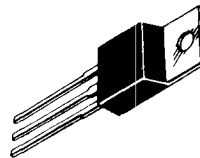
Characteristic	Symbol	Max.	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	1.47	°C/W

FIGURE 1 — POWER TEMPERATURE DERATING CURVE



DARLINGTON 15 AMPERE

COMPLEMENTARY SILICON
POWER TRANSISTORS
45-60-80-100-120 VOLTS
85 WATTS



NOTES

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIM Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	14.48	15.75	0.570	0.620
B	9.66	10.28	0.380	0.405
C	4.67	4.82	0.180	0.190
D	0.54	0.98	0.025	0.035
E	3.61	3.73	0.142	0.147
F	2.42	2.66	0.095	0.105
G	2.80	3.93	0.110	0.155
H	0.46	0.71	0.018	0.028
K	12.70	14.27	0.500	0.562
L	1.15	1.38	0.045	0.055
N	4.83	5.33	0.190	0.210
Q	2.54	3.04	0.100	0.120
R	2.04	2.79	0.080	0.110
S	1.15	1.38	0.045	0.055
T	5.97	6.47	0.235	0.255
U	0.00	1.27	0.000	0.050
V	1.15	—	0.045	—
Z	—	2.04	—	0.080

STYLE 1

1. BASE
2. COLLECTOR
3. EMITTER
4. COLLECTOR

CASE 221A-04
TO-220AB

**BDW39, BDW40, BDW41, BDW42, BDW43 NPN
BDW44, BDW45, BDW46, BDW47, BDW48 PNP**

ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector Emitter Sustaining Voltage (1) ($I_C = 30\text{ mAdc}$, $I_B = 0$)	$V_{CE(sus)}$	45 60 80 100 120	— — — — —	Vdc
Collector Cutoff Current ($V_{CE} = 22.5\text{ Vdc}$, $I_E = 0$) ($V_{CE} = 30\text{ Vdc}$, $I_E = 0$) ($V_{CE} = 40\text{ Vdc}$, $I_E = 0$) ($V_{CE} = 50\text{ Vdc}$, $I_E = 0$) ($V_{CE} = 60\text{ Vdc}$, $I_E = 0$)	I_{CEO}	— — — — —	2.0 2.0 2.0 2.0 2.0	mAdc
Collector Cutoff Current ($V_{CB} = 45\text{ Vdc}$, $I_E = 0$) ($V_{CB} = 60\text{ Vdc}$, $I_E = 0$) ($V_{CB} = 80\text{ Vdc}$, $I_E = 0$) ($V_{CB} = 100\text{ Vdc}$, $I_E = 0$) ($V_{CB} = 120\text{ Vdc}$, $I_E = 0$)	I_{CBO}	— — — — —	1.0 1.0 1.0 1.0 1.0	mAdc
Emitter Cutoff Current ($V_{BE} = 5.0\text{ Vdc}$, $I_C = 0$)	I_{EBO}	—	2.0	mAdc
ON CHARACTERISTICS (1)				
DC Current Gain ($I_C = 5.0\text{ Adc}$, $V_{CE} = 4.0\text{ Vdc}$) ($I_C = 10\text{ Adc}$, $V_{CE} = 4.0\text{ Vdc}$)	h_{FE}	1000 250	— —	
Collector-Emitter Saturation Voltage ($I_C = 5.0\text{ Adc}$, $I_B = 10\text{ mAdc}$) ($I_C = 10\text{ Adc}$, $I_B = 50\text{ mAdc}$)	$V_{CE(sat)}$	— —	2.0 3.0	Vdc
Base-Emitter On Voltage ($I_C = 10\text{ Adc}$, $V_{CE} = 4.0\text{ Vdc}$)	$V_{BE(on)}$	—	3.0	Vdc
SECOND BREAKDOWN (2)				
Second Breakdown Collector Current with Base Forward Biased BDW39/BDW40/BDW41/BDW42/BDW43 BDW44/BDW45/BDW46/BDW47/BDW48	$I_{S/b}$	3.0 1.2 3.8 1.2	— — — —	Adc
DYNAMIC CHARACTERISTICS				
Magnitude of common emitter small signal short circuit current transfer ratio ($I_C = 3.0\text{ Adc}$, $V_{CE} = 3.0\text{ Vdc}$, $f = 1.0\text{ MHz}$)	f_T	4.0	—	MHz
Output Capacitance ($V_{CB} = 10\text{ Vdc}$, $I_E = 0$, $f = 0.1\text{ MHz}$) BDW39/BDW40/BDW41/BDW42/BDW43 BDW44/BDW45/BDW46/BDW47/BDW48	C_{ob}	— —	200 300	pF
Small-Signal Current Gain ($I_C = 3.0\text{ Adc}$, $V_{CE} = 3.0\text{ Vdc}$, $f = 1.0\text{ kHz}$)	h_{fe}	300	—	

Indicates JEDEC Registered Data.

(1) Pulse Test: Pulse Width = $300\text{ }\mu\text{s}$, Duty Cycle = 2.0%.

(2) Pulse Test non repetitive: Pulse Width = 250 ms.

BDW39, BDW40, BDW41, BDW42, BDW43 NPN BDW44, BDW45, BDW46, BDW47, BDW48 PNP

FIGURE 2 – SWITCHING TIMES TEST CIRCUIT

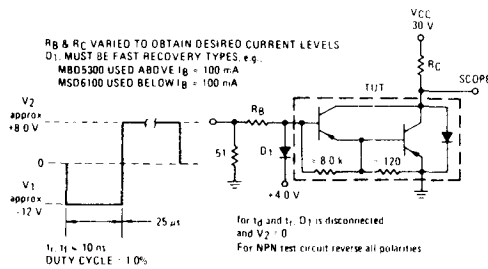


FIGURE 3 – SWITCHING TIMES

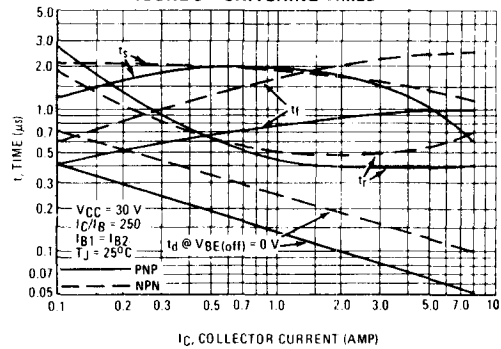
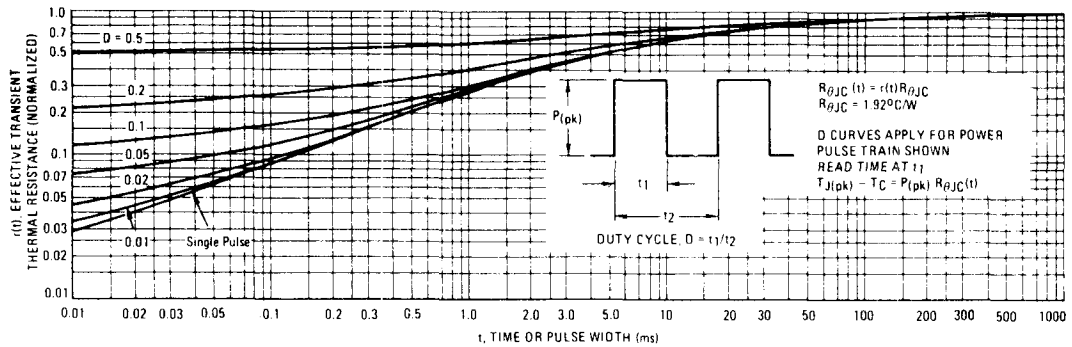
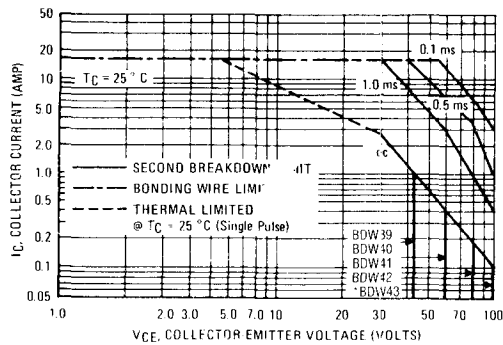


FIGURE 4 – THERMAL RESPONSE



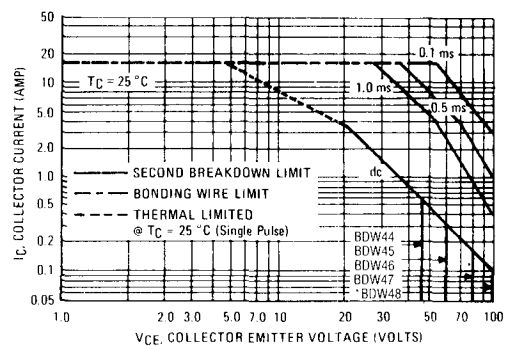
ACTIVE-REGION SAFE OPERATING AREA

FIGURE 5 – BDW39 THRU BDW43



There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate. The data of Fig. 5 and 6 is based on $T_{J(pk)} =$

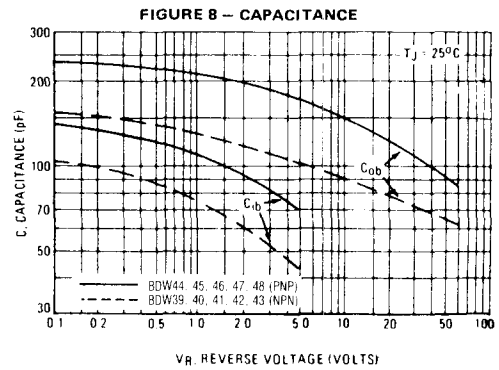
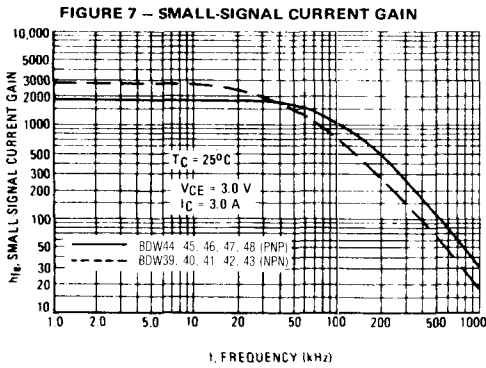
FIGURE 6 – BDW44 THRU BDW48



200 °C; T_C is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} \leq 200^\circ\text{C}$. $T_{J(pk)}$ may be calculated from the data in Fig. 4. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown. (See an-415).

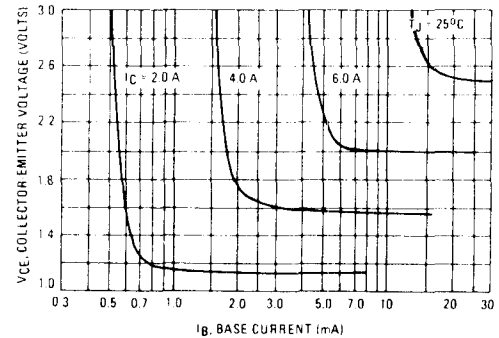
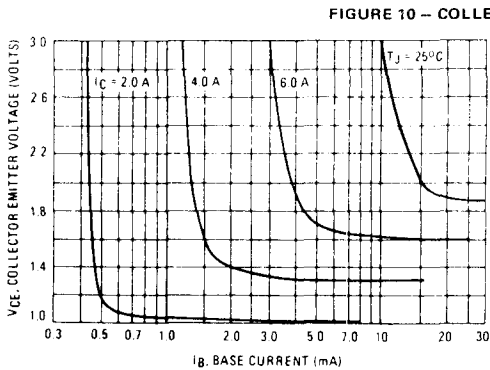
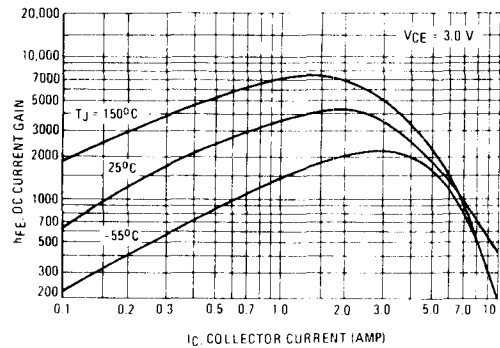
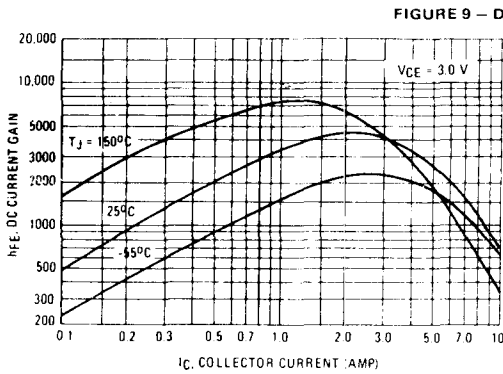
*Linear extrapolation

BDW39, BDW40, BDW41, BDW42, BDW43 NPN
BDW44, BDW45, BDW46, BDW47, BDW48 PNP



BDW39, 40, 41, 42, 43 (NPN)

BDW44, 45, 46, 47, 48 (PNP)



**BDW39, BDW40, BDW41, BDW42, BDW43 NPN
BDW44, BDW45, BDW46, BDW47, BDW48 PNP**

BDW39, 40, 41, 42, 43 (NPN)

BDW44, 45, 46, 47, 48 (PNP)

FIGURE 11 — "ON" VOLTAGES

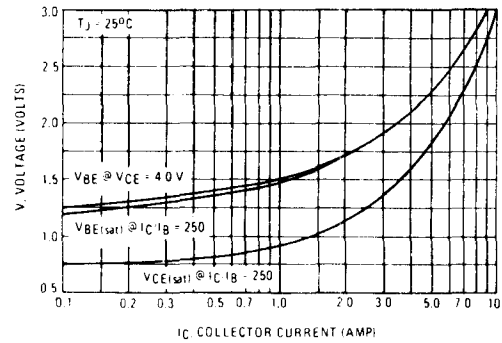
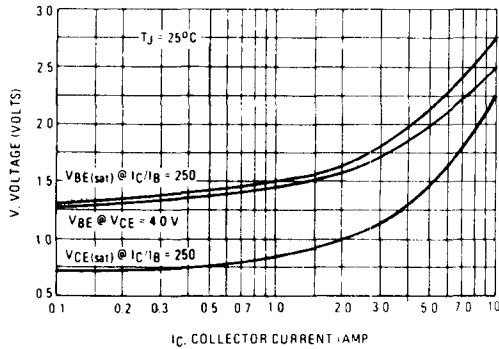


FIGURE 12 — TEMPERATURE COEFFICIENTS

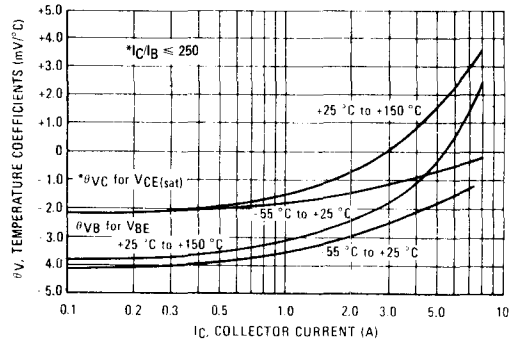
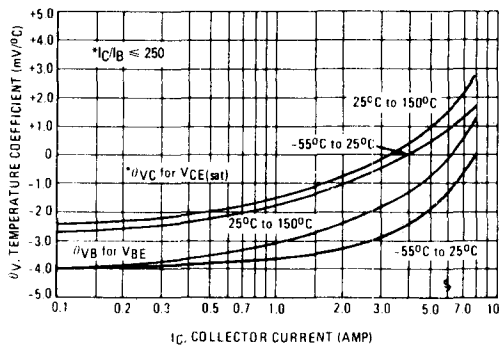
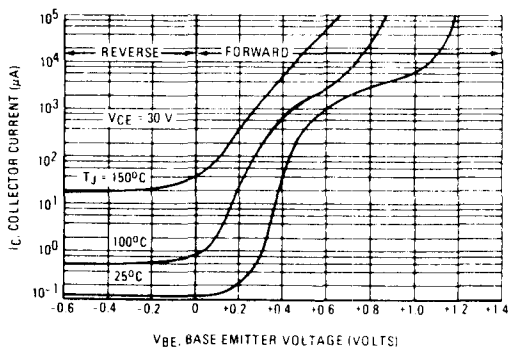
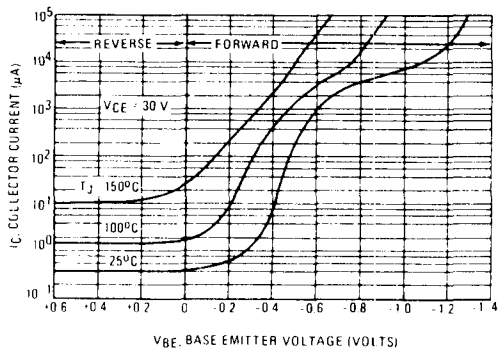


FIGURE 13 — COLLECTOR CUT-OFF REGION



BDW39, BDW40, BDW41, BDW42, BDW43 NPN
BDW44, BDW45, BDW46, BDW47, BDW48 PNP

FIGURE 14 — DARLINGTON SCHEMATIC

